



2SA2040/2SC5707

Bipolar Transistor (-50V, (-)8A, Low VCE(sat), (PNP)NPN Single TP/TP-FA

ON Semiconductor®

<http://onsemi.com>

Applications

- DC / DC converter, relay drivers, lamp drivers, motor drivers, flash

Features

- Adoption of FBET and MBIT processes
- Large current capacitance
- Low collector-to-emitter saturation voltage
- High-speed switching
- High allowable power dissipation

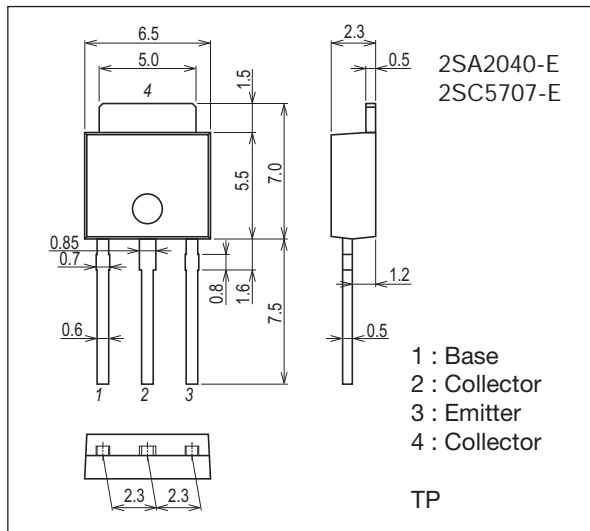
Specifications () : 2SA2040

Absolute Maximum Ratings at Ta=25°C

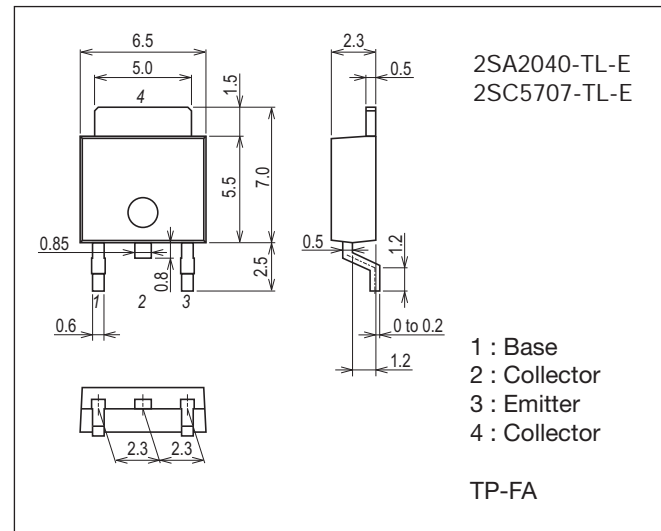
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		(-50)100	V
Collector-to-Emitter Voltage	V _{CES}		(-50)100	V
Collector-to-Emitter Voltage	V _{CEO}		(-50)	V
Emitter-to-Base Voltage	V _{EB0}		(-6)	V
Collector Current	I _C		(-8)	A
Collector Current (Pulse)	I _{CP}		(-11)	A

Continued on next page.

Package Dimensions unit : mm (typ) 7518-003



Package Dimensions unit : mm (typ) 7003-003

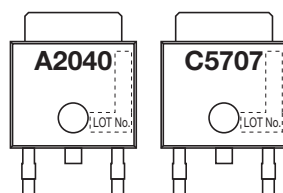


Product & Package Information

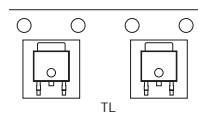
- Package : TP
- JEITA, JEDEC : SC-64, TO-251
- Minimum Packing Quantity : 500 pcs./bag

- Package : TP-FA
- JEITA, JEDEC : SC-63, TO-252
- Minimum Packing Quantity : 700 pcs./reel

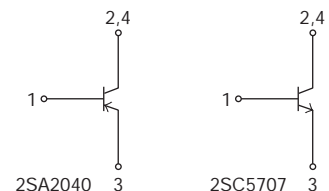
Marking (TP, TP-FA)



Packing Type (TP-FA) : TL



Electrical Connection



2SA2040 / 2SC5707

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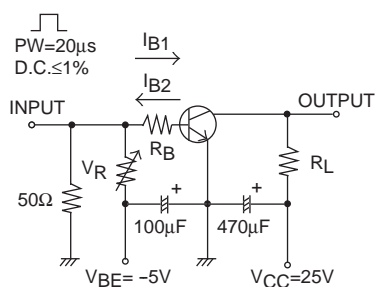
Parameter	Symbol	Conditions	Ratings	Unit
Base Current	I_B		(-)2	A
Collector Dissipation	P_C		1.0	W
		$T_C=25^\circ\text{C}$	15	W
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)40\text{V}, I_E=0\text{A}$			(-)0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4\text{V}, I_C=0\text{A}$			(-)0.1	μA
DC Current Gain	h_{FE}	$V_{CE}=(-)2\text{V}, I_C=(-)500\text{mA}$	200		560	
Gain-Bandwidth Product	f_T	$V_{CE}=(-)10\text{V}, I_C=(-)500\text{mA}$		(290)330		MHz
Output Capacitance	C_{ob}	$V_{CB}=(-)10\text{V}, f=1\text{MHz}$		(50)28		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)1}$	$I_C=(-)3.5\text{A}, I_B=(-)175\text{mA}$		(-230)160	(-390)240	mV
	$V_{CE(sat)2}$	$I_C=(-)2\text{A}, I_B=(-)40\text{mA}$		(-240)110	(-400)170	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)2\text{A}, I_B=(-)40\text{mA}$		(-)0.83	(-)1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu\text{A}, I_E=0\text{A}$	(-50)100			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CES}$	$I_C=(-)100\mu\text{A}, R_{BE}=0\Omega$	(-50)100			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1\text{mA}, R_{BE}=\infty$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu\text{A}, I_C=0\text{A}$	(-)6			V
Turn-On Time	t_{on}			(40)30		ns
Storage Time	t_{stg}	See specified Test Circuit.		(225)420		ns
Fall Time	t_f			25		ns

Switching Time Test Circuit

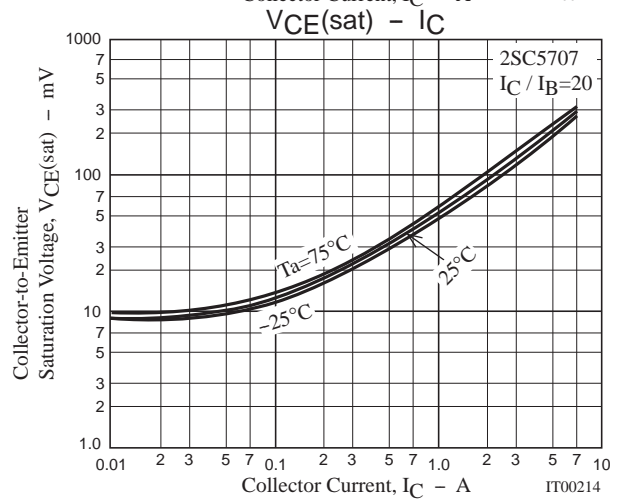
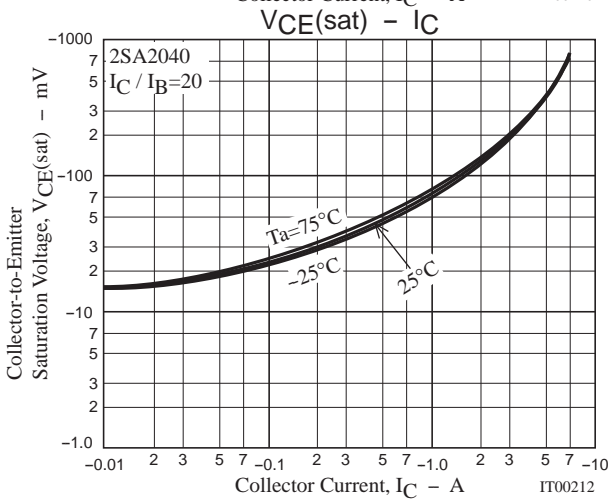
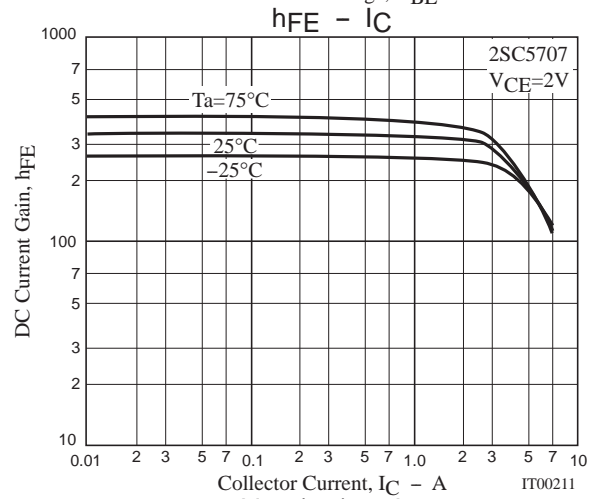
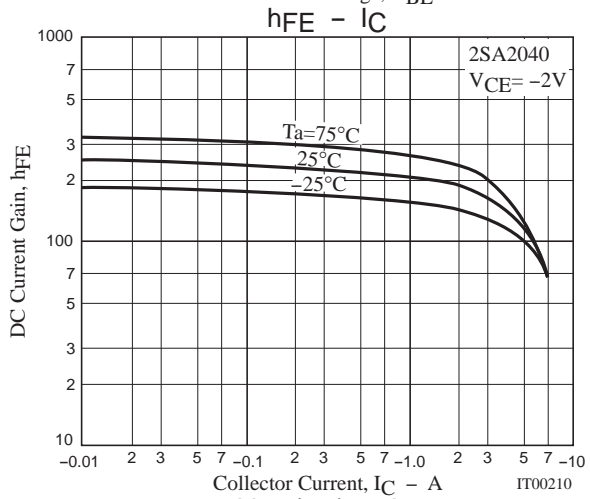
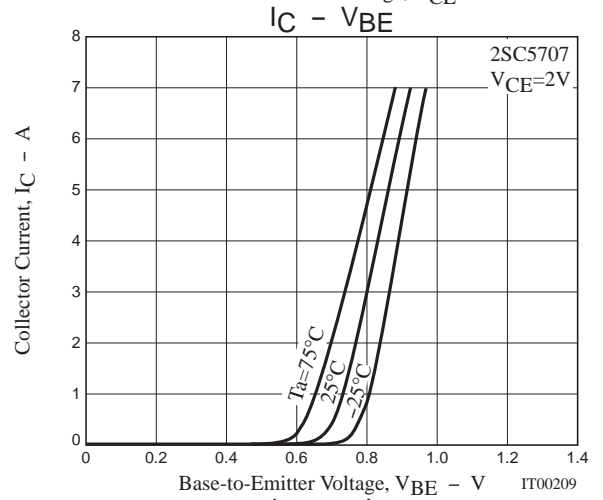
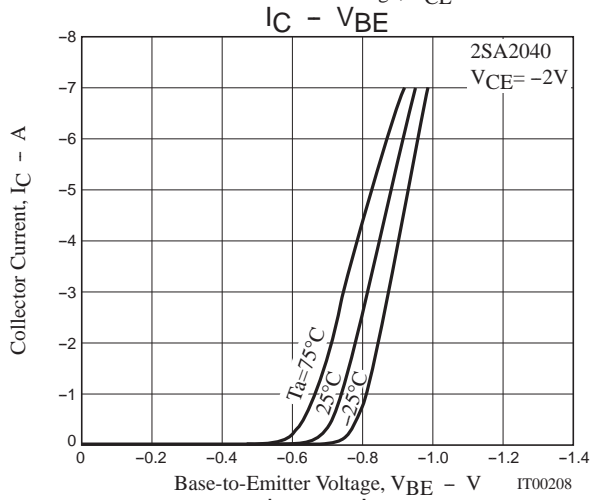
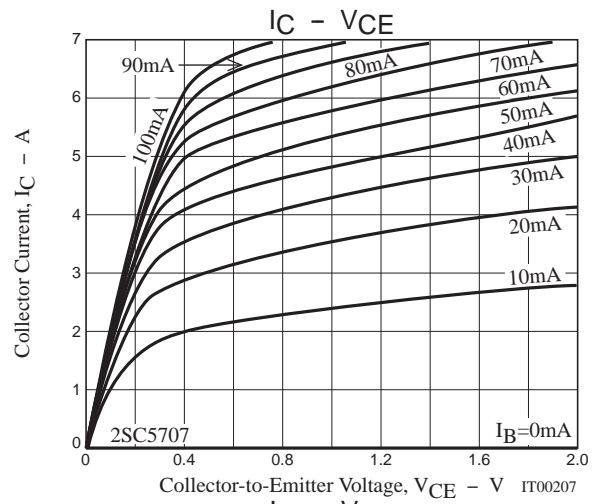
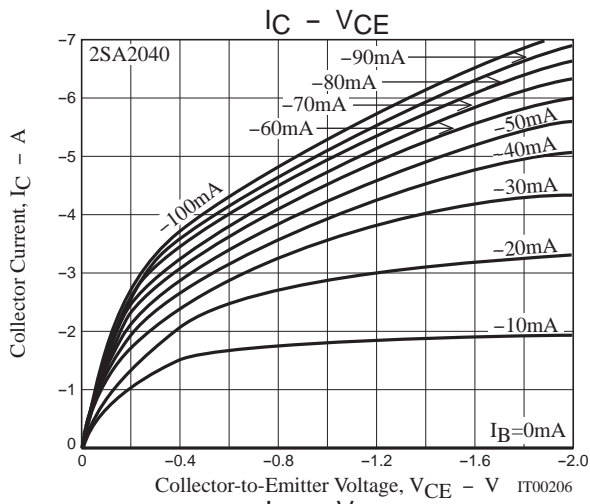


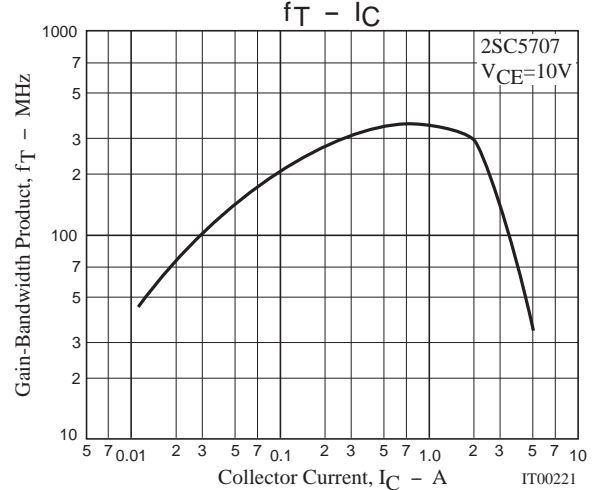
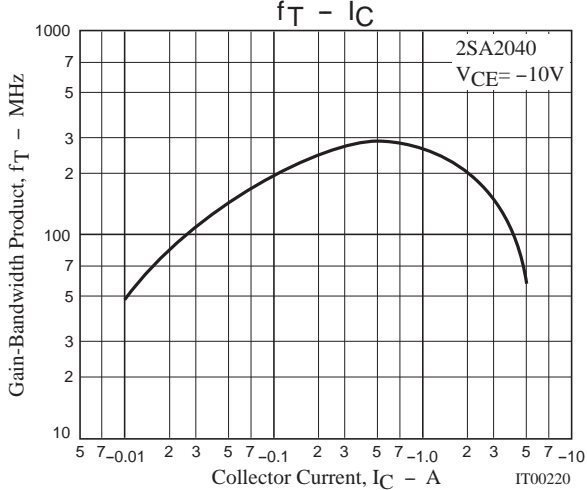
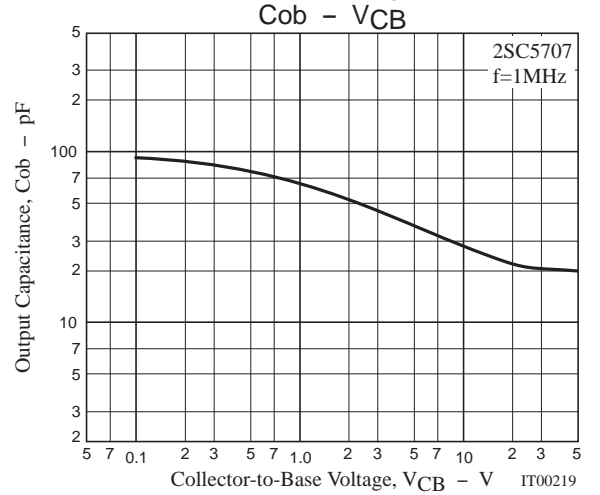
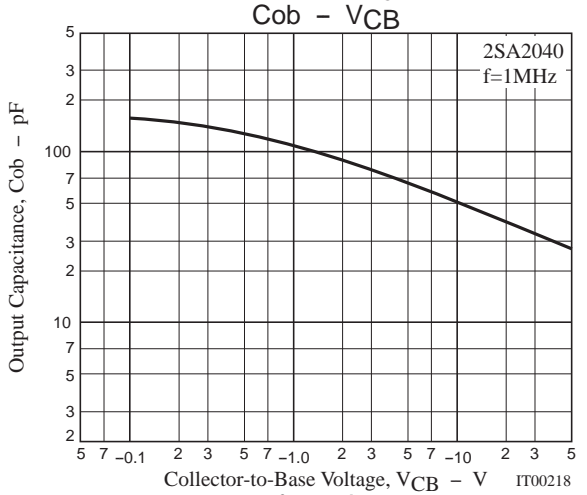
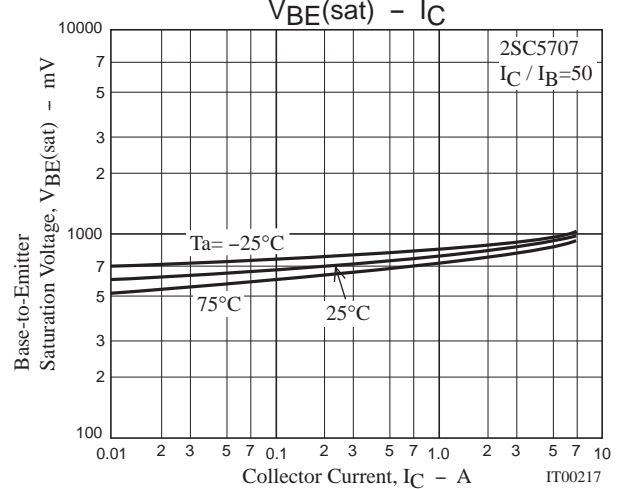
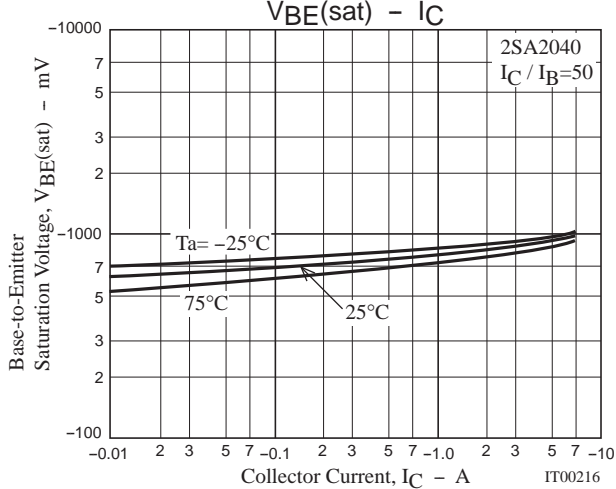
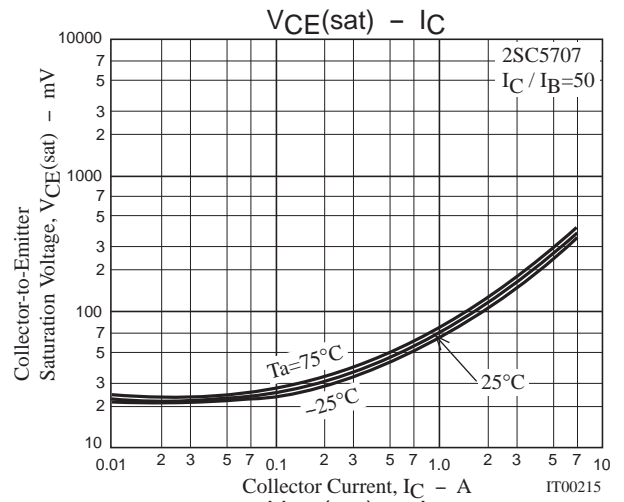
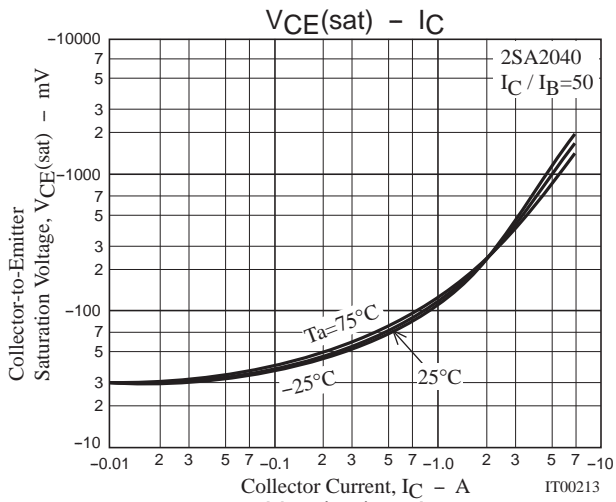
$$20I_{B1} = -20I_{B2} = I_C = 2.5\text{A}$$

For PNP, the polarity is reversed.

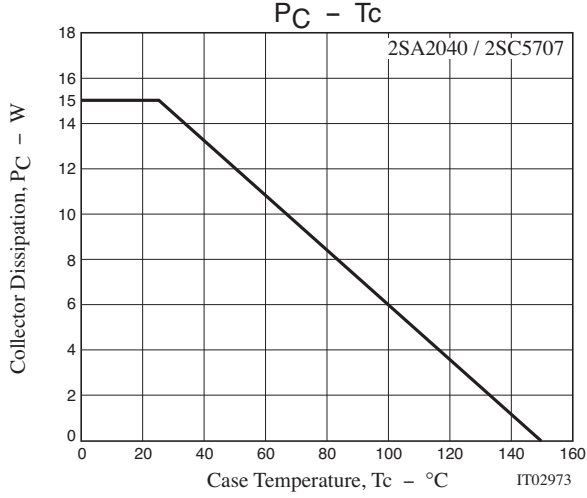
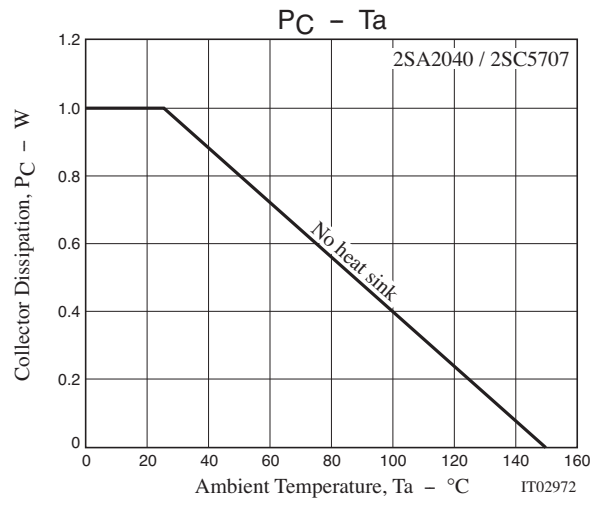
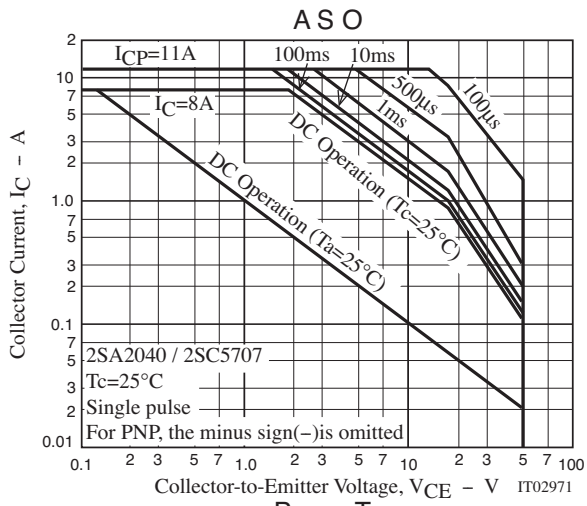
Ordering Information

Device	Package	Shipping	memo
2SA2040-E	TP	500pcs./bag	Pb Free
2SC5707-E	TP	500pcs./bag	
2SA2040-TL-E	TP-FA	700pcs./reel	
2SC5707-TL-E	TP-FA	700pcs./reel	





2SA2040 / 2SC5707



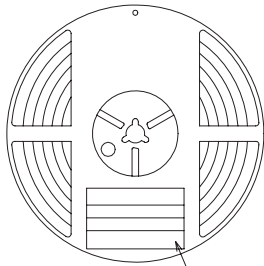
Taping Specification

2SA2040-TL-E, 2SC5707-TL-E

Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
TP-FA	TP	700	2,100	12,600	3 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

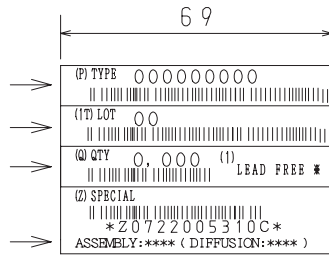
Packing method



Type No.
LOT No.
Quantity
Origin

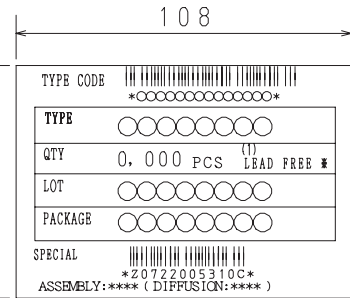
Reel label

Reel label, Inner box label (unit:mm)



Outer box label

It is a label at the time of factory shipments. The form of a label may change in physical distribution process.



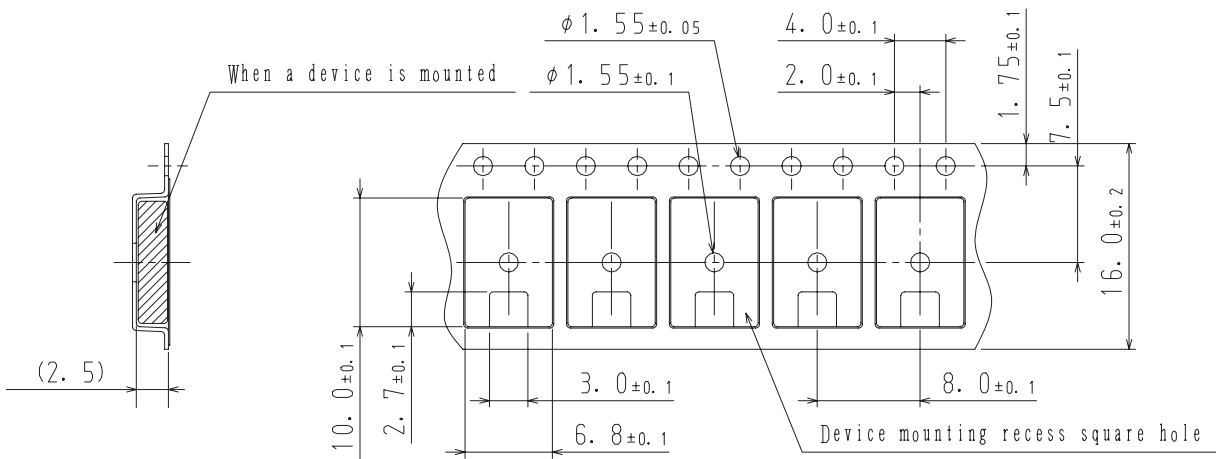
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

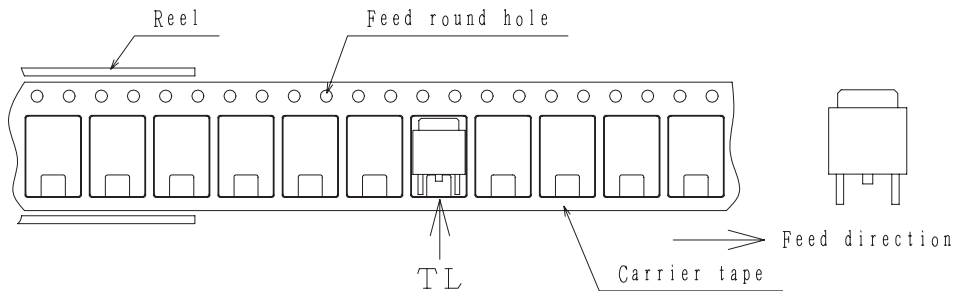
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

Taping configuration

1. Carrier tape size (unit:mm)



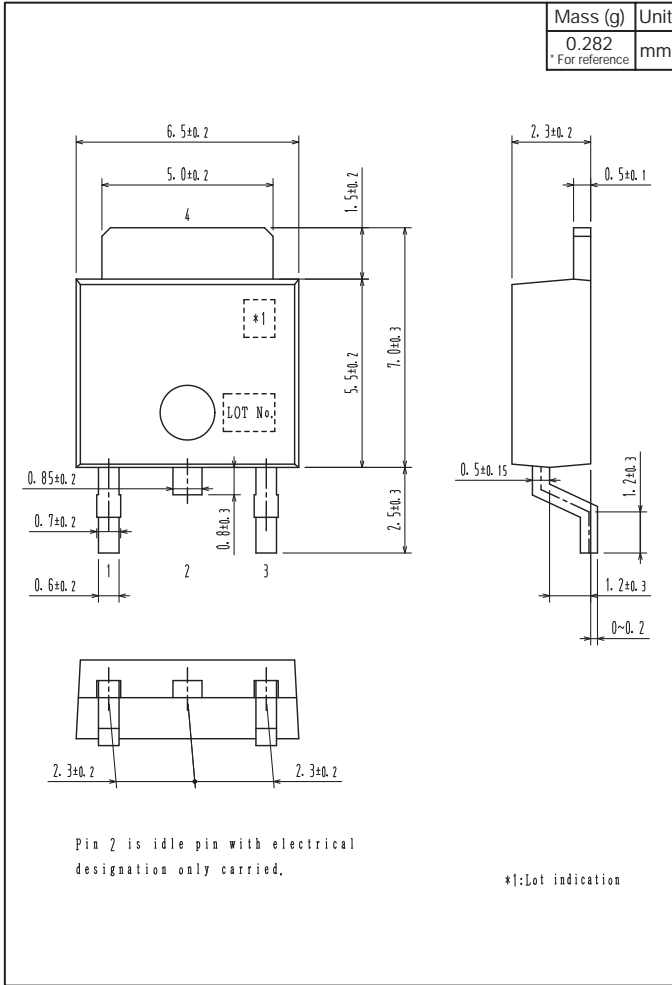
2. Device placement direction



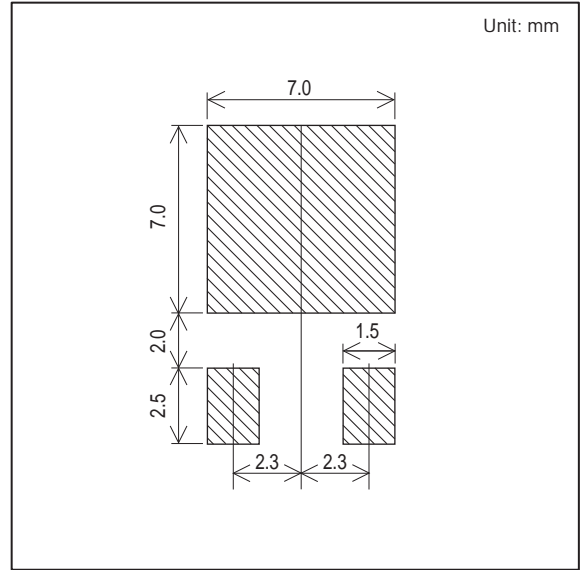
Those with one electrode terminal on the feed hole side.....TL

Outline Drawing

2SA2040-TL-E, 2SC5707-TL-E



Land Pattern Example



Bag Packing Specification

2SA2040-E, 2SC5707-E

1. Packing Format

Package Name	Maximum Number of devices contained (pcs)			
	Bag	Inner box	Outer box	
TP	500	B-1	A-1	A-2
		10,000	50,000	30,000
	Packing format (Dimensions:mm (external))			
		Inner box	Outer box	
		B-1	A-1	A-2
		445×225×55	470×250×300	470×250×190

2. Bag dimensions
(unit:mm)



3. Bag label, Inner box label
(unit:mm)



4. Outer box label
(unit:mm)

It is a label at the time of factory shipments.
The form of a label may change in physical
distribution process,

NOTE (1)

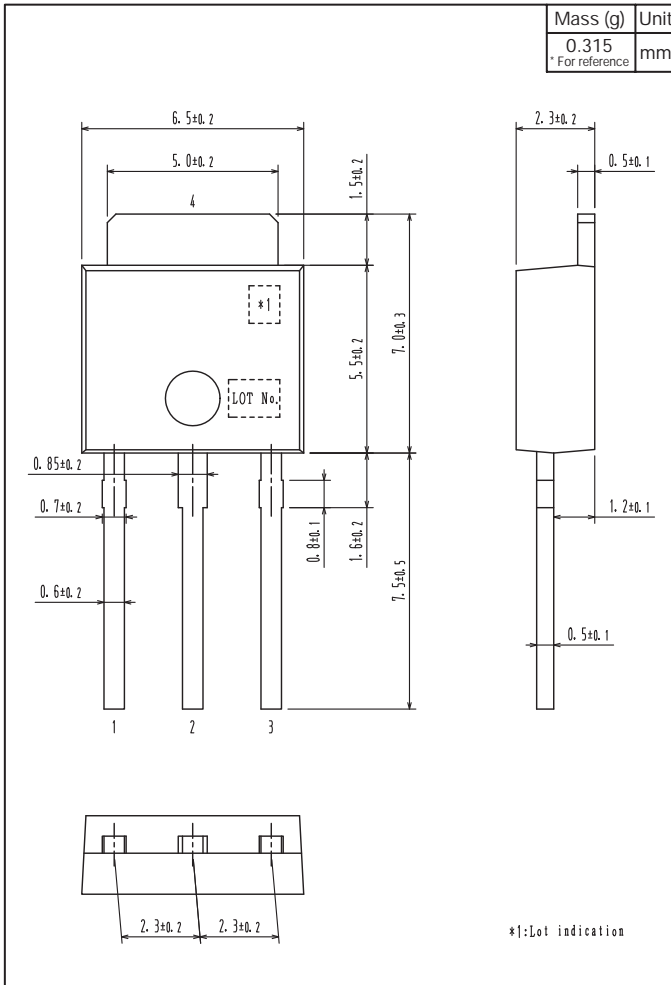
The LEAD FREE * description shows that the
surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3



Outline Drawing

2SA2040-E, 2SC5707-E



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